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**Correction: Understanding the physical basis of memory: Molecular mechanisms of the engram**

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Clara Ortega-de San Luis and Tomás J. Ryan

The authors report that in the review “Understanding the physical basis of memory: Molecular mechanisms of the engram” there were two grammatical errors in the fourth and in the last sentences in the second paragraph on page 14.

The correct sentences appear below.

The fourth sentence “On top of that, the system must assure that all this happens in an information-specific way—this is, only the relevant code-bearing cells, and not others, would be screened for that particular experience” should read “On top of that, the system must assure that all this happens in an information-specific way—that is, only the relevant code-bearing cells, and not others, would be screened for that particular experience.”

The last sentence “Although theoretically it might be feasible, substantial evidence would be necessary to validate such hypothetical mechanism” should read “Although theoretically it might be feasible, substantial evidence would be necessary to validate such a hypothetical mechanism”.